

ST6215L/25L

LOW VOLTAGE 8-BIT ROM MCUs WITH A/D CONVERTER AND 28 PINS

- 2.4 to 3.9V Supply Operating Range
- 4 MHz Maximum Clock Frequency
- 0 to +70°C Operating Temperature Range
- Run, Wait and Stop Modes
- 5 Interrupt Vectors
- Look-up Table capability in Program Memory
- Data Storage in Program Memory: User selectable size
- Data RAM: 64bytes
- 20 I/O pins, fully programmable as:
 - Input with pull-up resistor
 - Input without pull-up resistor
 - Input with interrupt generation
 - Open-drain or push-pull output
 - Analog Input
- 8 I/O lines can sink up to 12mA to drive LEDs
- 8-bit Timer/Counter with 7-bit programmable prescaler
- Digital Watchdog
- 8-bit A/D Converter with 16 analog inputs
- On-chip Clock oscillator can be driven by Quartz Crystal Ceramic resonator or RC network
- Power-on Reset
- One external Non-Maskable Interrupt
- ST626x-EMU2 Emulation and Development System (connects to an MS-DOS PC via an RS232 serial line)

PDIP28 PSO28

DEVICE SUMMARY

DEVICE	ROM (Bytes)
ST6215L	1836
ST6225L	3884

Rev. 1.0

November 1997 1/10

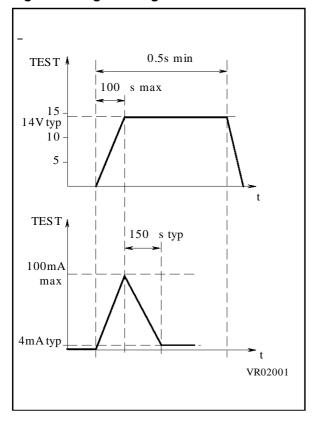
1 GENERAL DESCRIPTION

1.1 INTRODUCTION

The ST6215L/25L are low voltage mask programmed ROM version of ST62T15C,T25C OTP devices.

They offer the same functionality as OTP devices, selecting as ROM options the options defined in the programmable option byte of the OTP version, with the exception of the LVD Reset that is not available.

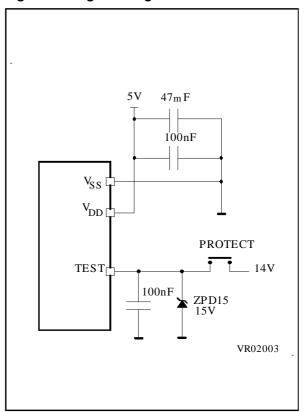
Figure 1. Programming wave form



1.2 ROM READOUT PROTECTION

If the ROM READOUT PROTECTION option is selected, a protection fuse can be blown to prevent any access to the program memory content. In case the user wants to blow this fuse, high voltage must be applied on the TEST pin.

Figure 2. Programming Circuit



Note: ZPD15 is used for overvoltage protection

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	ST621	5L/25L MICROCONT	ROLLER OPTION LIST
Customer Address			
Contact Phone No Reference			
SGS-THON	ASON Microelec	tronics references	
Device: Package:	NOON MIGISTRE	[]ST6215L	[] ST6225L c[] Small Outline Plastic with conditionning: [] Standard (Stick) [] Tape & Reel
Temperatui Special Ma	-	[] 0°C to + 70°C [] No	[]Yes ""
	characters are l character count:	etters, digits, '.', '-', '/' DIP28: SO28:	and spaces only. 10 8
Oscillator S	Source Selection	: [] Crystal Quartz/Ce [] RC Network	•
Watchdog	Selection:	[] Software Activatio [] Hardware Activatio	
ROM Read	lout Protection:	[] Disabled (Fuse ca	nnot be blown) n be blown by the customer)
Note:		No part is delivered to The fuse must be bloom	with protected ROM. own for protection to be effective.
External ST	ΓΟΡ Mode Cont	ro[] Enabled	[] Disabled
TIMER pin NMI pin pul		[] Enabled [] Enabled	[] Disabled [] Disabled
	erating Range in equency in the	the application: application:	



1.3 ORDERING INFORMATION

The following section deals with the procedure for transfer of customer codes to SGS-THOMSON.

1.3.1 Transfer of Customer Code

Customer code is made up of the ROM contents and the list of the selected mask options. The ROM contents are to be sent on diskette, or by electronic means, with the hexadecimal file generated by the development tool. All unused bytes must be set to FFh.

The selected mask options are communicated to SGS-THOMSON using the correctly filled OP-TION LIST appended.

1.3.2 Listing Generation and Verification

When SGS-THOMSON receives the user's ROM contents, a computer listing is generated from it. This listing refers exactly to the mask which will be used to produce the specified MCU. The listing is then returned to the customer who must thoroughly check, complete, sign and return it to SGS-THOMSON. The signed listing forms a part of the contractual agreement for the creation of the specific customer mask.

The SGS-THOMSON Sales Organization will be pleased to provide detailed information on contractual points.

Table 1. ROM Memory Map for ST6215L

Device Address	Description
0000h-087Fh	Reserved
0880h-0F9Fh	User ROM
0FA0h-0FEFh	Reserved
0FF0h-0FF7h	Interrupt Vectors
0FF8h-0FFBh	Reserved
0FFCh-0FFDh	NMI Interrupt Vector
0FFEh-0FFFh	Reset Vector

Table 2. ROM Memory Map for ST6225L

Device Address	Description
0000h-007Fh	Reserved
0080h-0F9Fh	User ROM
0FA0h-0FEFh	Reserved
0FF0h-0FF7h	Interrupt Vectors
0FF8h-0FFBh	Reserved
0FFCh-0FFDh	NMI Interrupt Vector
0FFEh-0FFFh	Reset Vector

Table 3. ROM version Ordering Information

Sales Type	ROM	Temperature Range	Package
ST6215LB1/XXX	1836 Bytes		PDIP28
ST6215LM1/XXX	1030 Bytes	0 to +70°C	PSO28
ST6225LB1/XXX	2004 Putos	0 10 +70 C	PDIP28
ST6225LM1/XXX	3884 Bytes		PSO28

2 ELECTRICAL CHARACTERISTICS

2.1 ABSOLUTE MAXIMUM RATINGS

This product contains devices to protect the inputs against damage due to high static voltages, however it is advisable to take normal precaution to avoid application of any voltage higher than the specified maximum rated voltages.

For proper operation it is recommended that $V_{\rm and}$ $V_{\rm O}$ be higher than $V_{\rm SS}$ and lower than $V_{\rm DD}$. Reliability is enhanced if unused inputs are connected to an appropriate logic voltage level ($V_{\rm DD}$ or $V_{\rm SS}$).

Power Considerations. The average chip-junction temperature, Tj, in Celsius can be obtained from:

Tj=TA + PD x RthJA

Where:TA = Ambient Temperature.

RthJA =Package thermal resistance (junction-to ambient).

PD = Pint + Pport.

Pint =IDD x VDD (chip internal power).

Pport =Port power dissipation (determined by the user).

Symbol	Parameter	Value	Unit
V_{DD}	Supply Voltage	-0.3 to 7.0	V
V _I	Input Voltage	V_{SS} - 0.3 to V_{DD} + 0.3 ⁽¹⁾	V
V _O	Output Voltage	V_{SS} - 0.3 to V_{DD} + 0.3 ⁽¹⁾	V
I _O	Current Drain per Pin Excluding V _{DD} , V _{SS}	±10	mA
IV_{DD}	Total Current into V _{DD} (source)	50	mA
IV _{SS}	Total Current out of V _{SS} (sink)	50	mA
Tj	Junction Temperature	150	°C
T _{STG}	Storage Temperature	-60 to 150	°C

Notes:

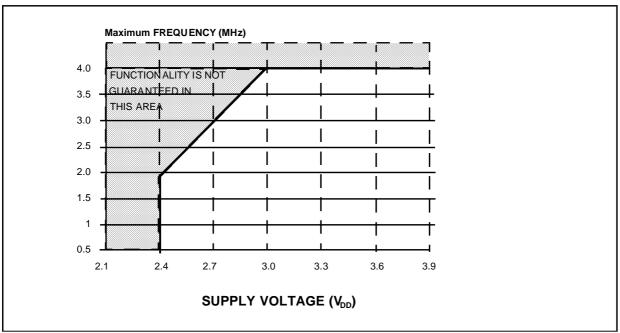
- Stresses above those listed as "absolute maximum ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these conditions is not implied. Exposure to maximum rating conditions for extended periods may affect device reliability.
- (1) Within these limits clamping diodes are guarantee to be not conductive. Voltages outside these limits are authorised as long as injection current is kept within the specification.

2.2 RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Test Conditions		Unit		
Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Oill
T _A	Operating Temperature	1 Suffix Version	0		70	°C
V _{DD}	Operating Supply Voltage	$f_{OSC} = 2MHz$ $f_{OSC} = 4MHz$	2.4 3		3.9 3.9	V
fosc	Oscillator Frequency ²⁾	$V_{DD} = 2.4V$ $V_{DD} = 3.0V$	0		2.0 4.0	MHz
I _{INJ+}	Pin Injection Current (positive)	$V_{DD} = 2.4 \text{ to } 3.9 \text{V}$			+5	mA
I _{INJ-}	Pin Injection Current (negative)	$V_{DD} = 2.4 \text{ to } 3.9 \text{V}$			-5	mA

Notes:

Figure 3. Maximum Operating FREQUENCY (Fmax) Versus SUPPLY VOLTAGE (YD)



The shaded area is outside the recommended operating range; device functionality is not guaranteed under these conditions.

^{1.} Care must be taken in case of negative current injection, where adapted impedance must be respected on analog sources to not affect the A/D conversion. For a -1mA injection, a maximum $10~{\rm K}\Omega$ is recommended.

^{2.}An oscillator frequency above 1MHz is recommended for reliable A/D results

2.3 DC ELECTRICAL CHARACTERISTICS

 $(T_A = 0 \text{ to } +70^{\circ}\text{C} \text{ unless otherwise specified})$

				Value		l
Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
V _{IL}	Input Low Level Voltage All Input pins				V _{DD} x 0.2	V
V _{IH}	Input High Level Voltage All Input pins		V _{DD} x 0.8			V
V _{Hys}	Hysteresis Voltage ⁽¹⁾ All Input pins	V _{DD} = 3V	0.2			V
	Low Level Output Voltage All Output pins	$\begin{aligned} & V_{DD} = 3.0V; I_{OL} = +10 \mu A \\ & V_{DD} = 3.0V; I_{OL} = +3.0 mA \\ & V_{DD} = 2.4V; I_{OL} = +1.5 mA \end{aligned}$			0.1 0.8 0.8	
V _{OL}	Low Level Output Voltage 20 mA Sink I/O pins	V_{DD} = 3.0V; I_{OL} = +10 μ A V_{DD} = 3.0V; I_{OL} = +8mA V_{DD} = 3.0V; I_{OL} = +12mA V_{DD} = 2.4V; I_{OL} = +5mA			0.1 0.8 1.3 0.8	V
V _{OH}	High Level Output Voltage All Output pins	V_{DD} = 3.0V; I_{OH} = -10 μ A V_{DD} = 3.0V; I_{OH} = -1.5mA V_{DD} = 2.4V; I_{OH} = -10 μ A	2.9 2.0 2.3			V
R _{PU}	Pull-up Resistance	All Input pins	100	250	600	ΚΩ
1490	'	RESET pin	400	600	1200	11.32
I _{IL}	Input Leakage Current All Input pins but RESET	$V_{IN} = V_{SS}$ (No Pull-Up configured) $V_{IN} = V_{DD}$		0.1	1.0	μΑ
I _{IH}	Input Leakage Current RESET pin	$V_{IN} = V_{SS}$ $V_{IN} = V_{DD}$	-8	-16	-30 10	μΛ
	Supply Current in RESET Mode	V _{RESET} =V _{SS} f _{OSC} =4MHz			1.5	mA
	Supply Current in RUN Mode ⁽²⁾	V _{DD} =3.0V f _{INT} =4MHz			1.5	mA
I _{DD}	Supply Current in WAIT Mode ⁽³⁾	V _{DD} =3.0V f _{INT} =4MHz			0.5	mA
	Supply Current in STOP Mode ⁽³⁾	I _{LOAD} =0mA V _{DD} =3.0V			2	μА

Notes:

- (1) Hysteresis voltage between switching levels
- (2) All peripherals running
- (3) All peripherals in stand-by

DC ELECTRICAL CHARACTERISTICS(Cont'd)

2.4 AC ELECTRICAL CHARACTERISTICS

 $((T_A = 0 \text{ to } +70^{\circ}\text{C unless otherwise specified})$

Symbol	Parameter	Test Conditions Value			Unit	
	Faiailletei	rest Conditions	Min.	Тур.	Max.	Offic
t _{REC}	Supply Recovery Time (1)		100			ms
f _{RC}	Internal frequency with RC oscillator ^{2) 3)}	VDD=3.0V R=47kΩ R=100kΩ R=470kΩ	2.5 1.4 450	3 1.7 520	3.5 2.1 600	MHz MHz kHz
C _{IN}	Input Capacitance	All Inputs Pins			10	pF
C _{OUT}	Output Capacitance	All Outputs Pins			10	pF

Notes: 1. Period for which V_{DD} has to be connected at 0V to allow internal Reset function at next power-up.

² An oscillator frequency above 1MHz is recommended for reliable A/D results.

^{3.} Measure performed with OSCin pin soldered on PCB, with an around 2pF equivalent capacitance.

2.5 A/D CONVERTER CHARACTERISTICS

 $(T_A = 0 \text{ to } +70^{\circ}\text{C unless otherwise specified})$

Symbol	Parameter	Test Conditions		Value		Unit
Symbol	Farameter	rest Conditions	Min.	Тур.	Max.	
Res	Resolution			8		Bit
A _{TOT}	Total Accuracy (1) (2)	$\begin{array}{l} f_{\rm OSC} > 1.2 {\rm MHz}, \ V_{\rm DD} {=} 3.0 {\rm V} \\ f_{\rm OSC} > 1.2 {\rm MHz}, \ V_{\rm DD} {=} 2.4 {\rm V} \\ f_{\rm OSC} > 32 {\rm kHz}, \ V_{\rm DD} {=} 3.0 {\rm V} \end{array}$			±25 ±35 ±50	mV
t _C	Conversion Time	$f_{OSC} = 2MHz$ $f_{OSC} = 4 MHz$		280 140		μs
ZIR	Zero Input Reading	Conversion result when $V_{IN} = V_{SS}$	00			Hex
FSR	Full Scale Reading	Conversion result when $V_{IN} = V_{DD}$			FF	Hex
ADI	Analog Input Current During Conversion	V _{DD} = 4.0V			1.0	μΑ
AC _{IN}	Analog Input Capacitance			2	5	pF

- Notes:
 1. Noise at VDD, VSS <10mV
 2. With oscillator frequencies less than 1MHz, the A/D Converter accuracy is decreased.

2.6 TIMER CHARACTERISTICS

 $((T_A = 0 \text{ to } +70^{\circ}\text{C unless otherwise specified})$

Symbol	Parameter	Test Conditions		Unit		
Symbol	Parameter Test Conditions		Min.	Тур.	Max.	Oilit
f _{IN}	Input Frequency on TIMER Pin					MHz
t _W	Pulse Width at TIMER Pin	$V_{DD} = 2.4V$	250			ns

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•		IJL	<i>, </i>

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